

TOSHIBA BIPOLEAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA75071P, TA75071S

SINGLE OPERATIONAL AMPLIFIER

The TA75071P and TA75071S are J-FET input low-noise operational amplifiers with low input bias and offset current, fast slew rate and wide bandwidth.

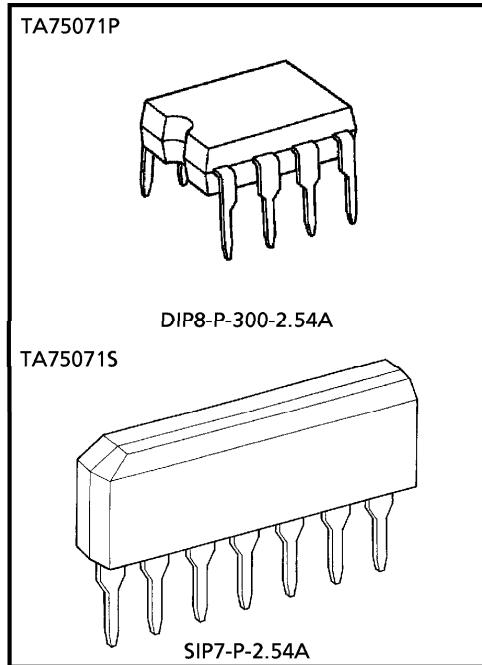
The TA75071P is pin compatible with the TA7504P and 741.

The TA75071S is single-in-line package.

The TA75071P series are excellent choice for active filters, integrators, buffers and sample-and-hold circuits.

FEATURES

- Low Input Bias Current : 200pA MAX.
- Low Input Offset Current : 50pA MAX.
- High Slew Rate : 13V / μ s
- Low Noise : 18nV / $\sqrt{\text{Hz}}$
- Wide Bandwidth : 3MHz
- Wide Supply Voltage Range : $\pm 4 \sim \pm 18$ V
- Internal Frequency Compensation
- Output Short Circuit Protection
- Offset Null Capability

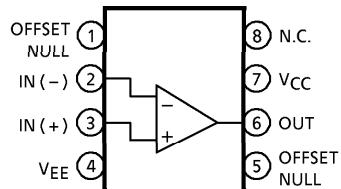


Weight

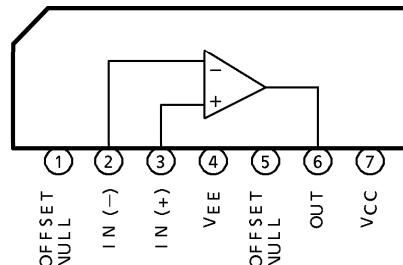
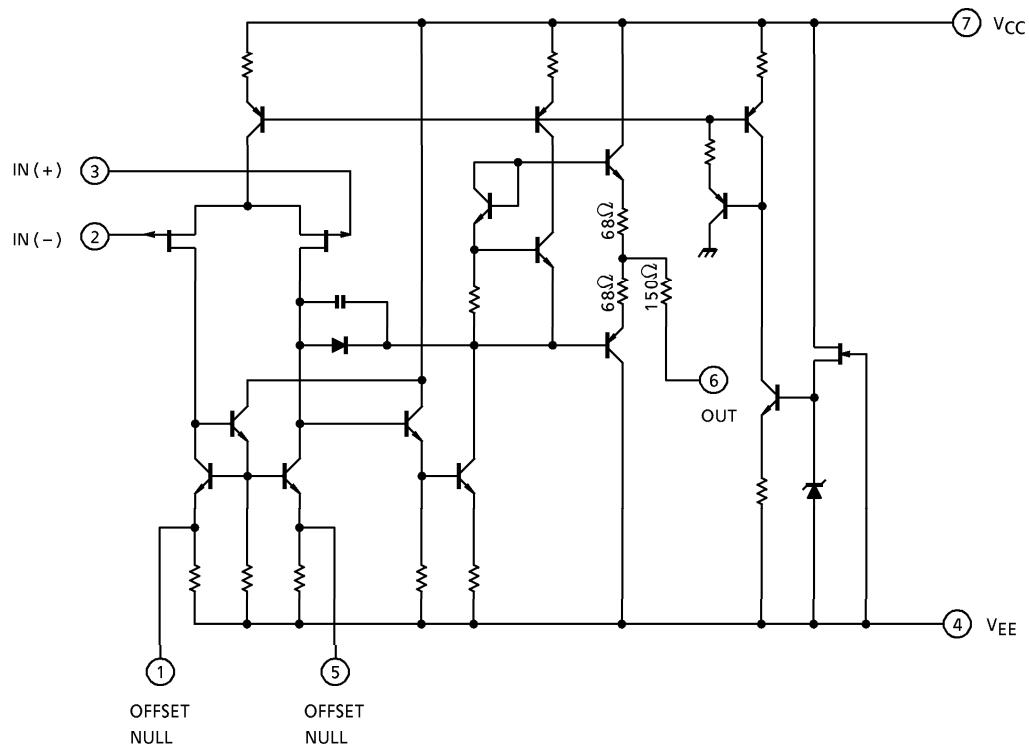
DIP8-P-300-2.54A : 0.5g (Typ.)
SIP7-P-2.54A : 0.7g (Typ.)

PIN CONNECTION (TOP VIEW)

TA75071P



TA75071S

**EQUIVALENT CIRCUIT**

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	+ 18	V
	V_{EE}	- 18	
Supply Voltage Surge)	DV_{IN}	± 30	V
Input Voltage	V_{IN}	± 15	V
Power Dissipation	P_D	500	mW
Operating Temperature	T_{opr}	- 40~85	$^\circ\text{C}$
Storage Temperature	T_{stg}	- 50~125	$^\circ\text{C}$

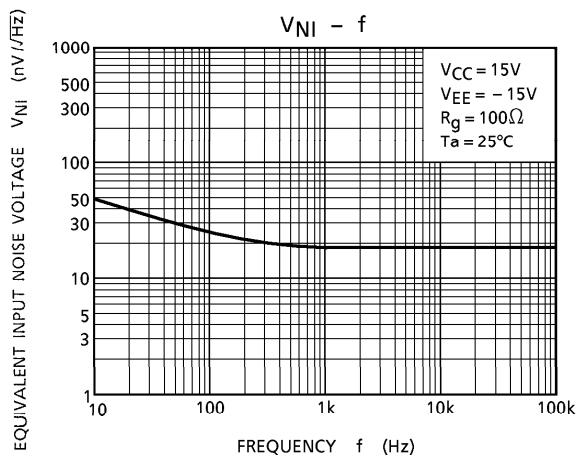
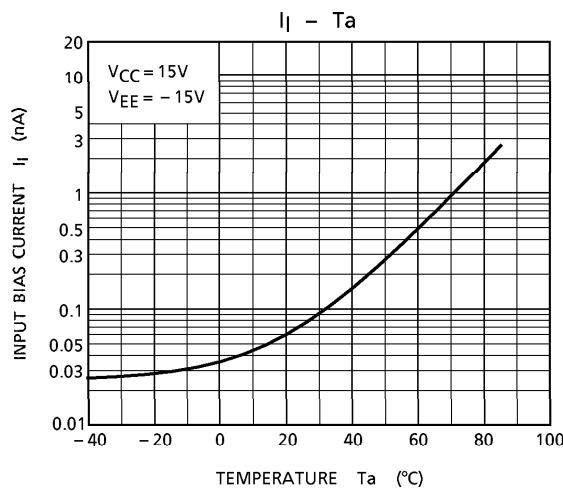
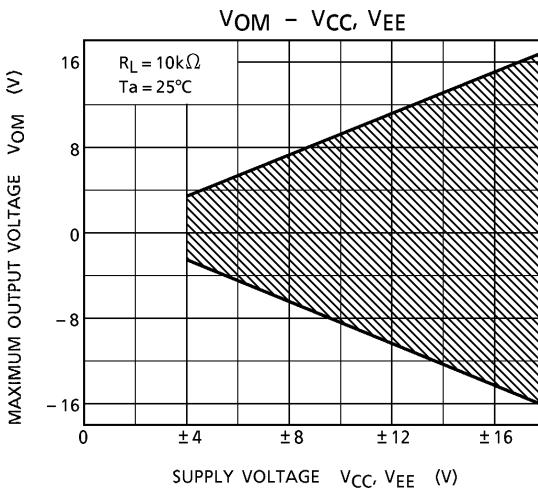
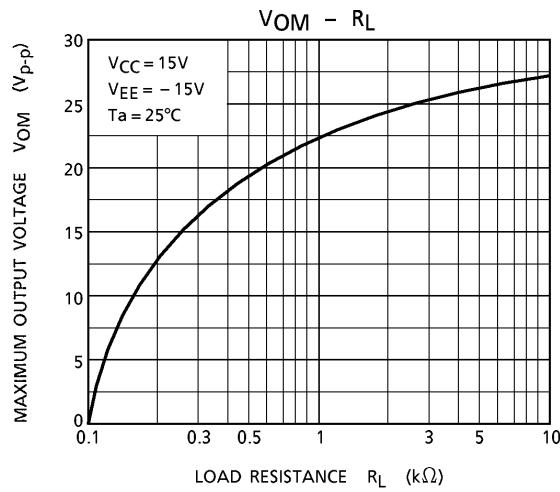
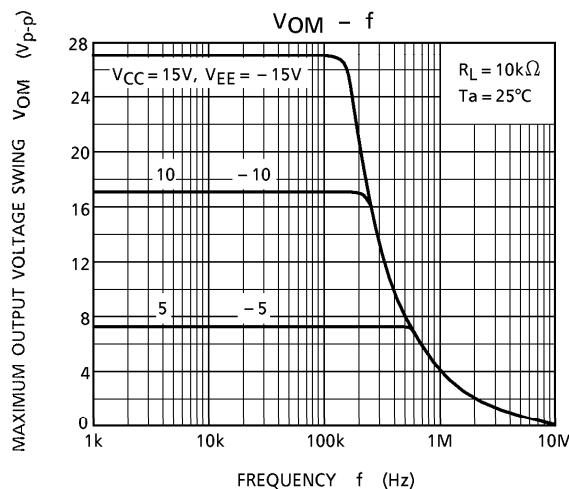
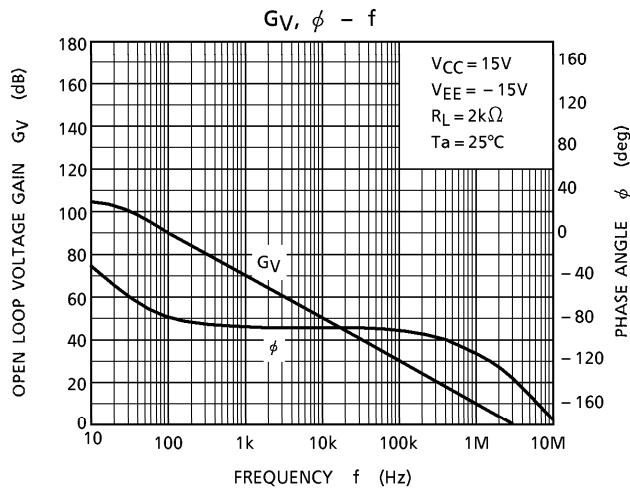
ELECTRICAL CHARACTERISTICS ($V_{CC} = 15\text{V}$, $V_{EE} = - 15\text{V}$, $T_a = 25^\circ\text{C}$)

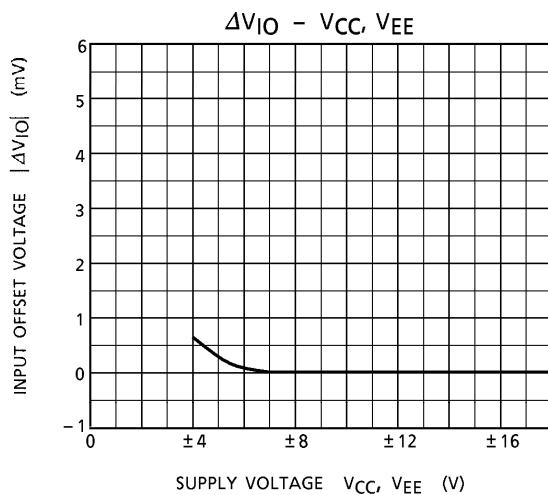
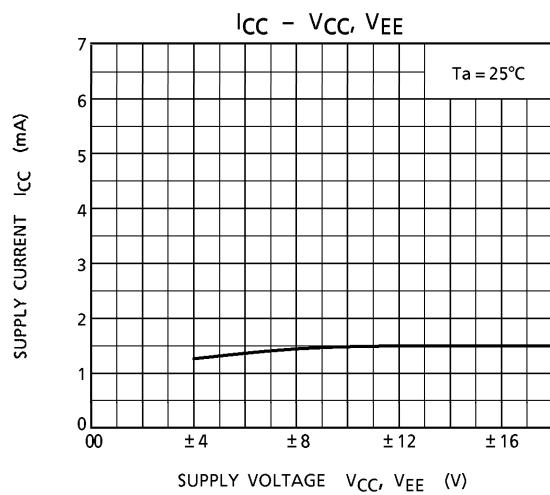
CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{IO}	—	$R_g \leq 10\text{k}\Omega$	—	3	10	mV
TC Of Input Offset Voltage	TCV_{IO}	—	—	—	10	—	$\mu\text{V}/^\circ\text{C}$
Input Offset Current	I_{IO}	—	—	—	10	50	pA
Input Bias Current	I_I	—	—	—	30	200	pA
Common Mode Input Voltage	CMV_{IN}	—	—	± 11	± 12	—	V
Maximum Output Voltage	V_{OM}	—	$R_L = 10\text{k}\Omega$	24	—	—	$\text{V}_{\text{p-p}}$
	V_{OMR}	—	$R_L = 2\text{k}\Omega$	20	24	—	
Voltage Gain (Open Loop)	G_V	—	$V_{OUT} = \pm 10\text{V}$, $R_L = 2\text{k}\Omega$	25	200	—	V / mV
Unity Gain Cross Frequency	f_T	—	Open Loop, $R_L = 10\text{k}\Omega$	—	3	—	MHz
Input Resistance	R_{IN}	—	—	—	10^{12}	—	Ω
Common Mode Input Signal Rejection Ratio	CMRR	—	$R_g \leq 10\text{k}\Omega$	70	76	—	dB
Supply Voltage Rejection Ratio	SVRR	—	$R_g \leq 10\text{k}\Omega$	70	76	—	dB
Supply Current	I_{CC} , I_{EE}	—	Non Load	—	1.4	2.5	mA

OPERATING CHARACTERISTICS ($V_{CC} = 15\text{V}$, $V_{EE} = - 15\text{V}$, $T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	—	$V_{IN} = 10\text{V}_{\text{p-p}}$, $R_L = 2\text{k}\Omega$ $C_L = 100\text{pF}$	—	13	—	$\text{V}/\mu\text{s}$
Equivalent Input Noise Voltage	V_{NI}	—	$R_S = 100\Omega$	$f = 1\text{kHz}$	—	18	$\text{nV}/\sqrt{\text{Hz}}$
				$f = 10\text{Hz} \sim 10\text{kHz}$	—	4	μV_{rms}
Equivalent Input Noise Current	I_{NI}	—	$R_S = 100\Omega$, $f = 1\text{kHz}$	—	0.01	—	$\text{pA}/\sqrt{\text{Hz}}$
Total Harmonic Distortion	THD	—	$V_{OUT} = 10\text{V}_{\text{rms}}$, $R_S \leq 1\text{k}\Omega$ $R_L \geq 2\text{k}\Omega$, $f = 1\text{kHz}$	—	0.01	—	%

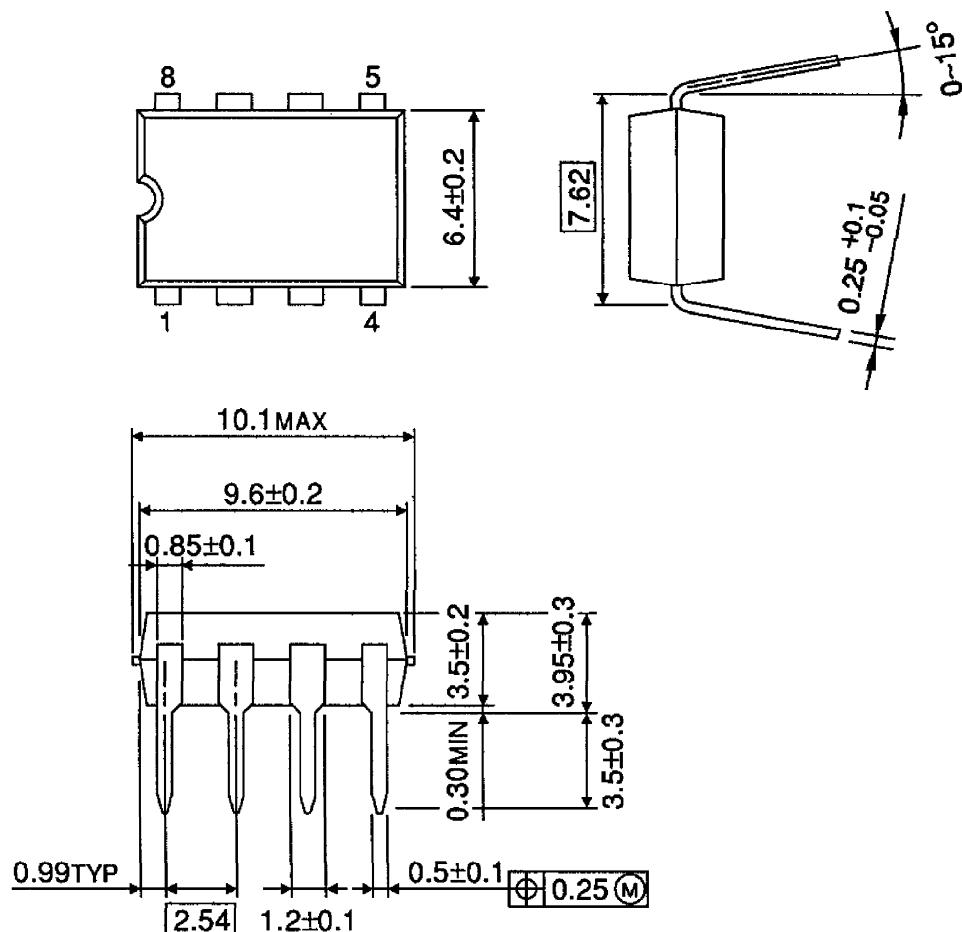
CHARACTERISTICS





PACKAGE DIMENSIONS
DIP8-P-300-2.54A

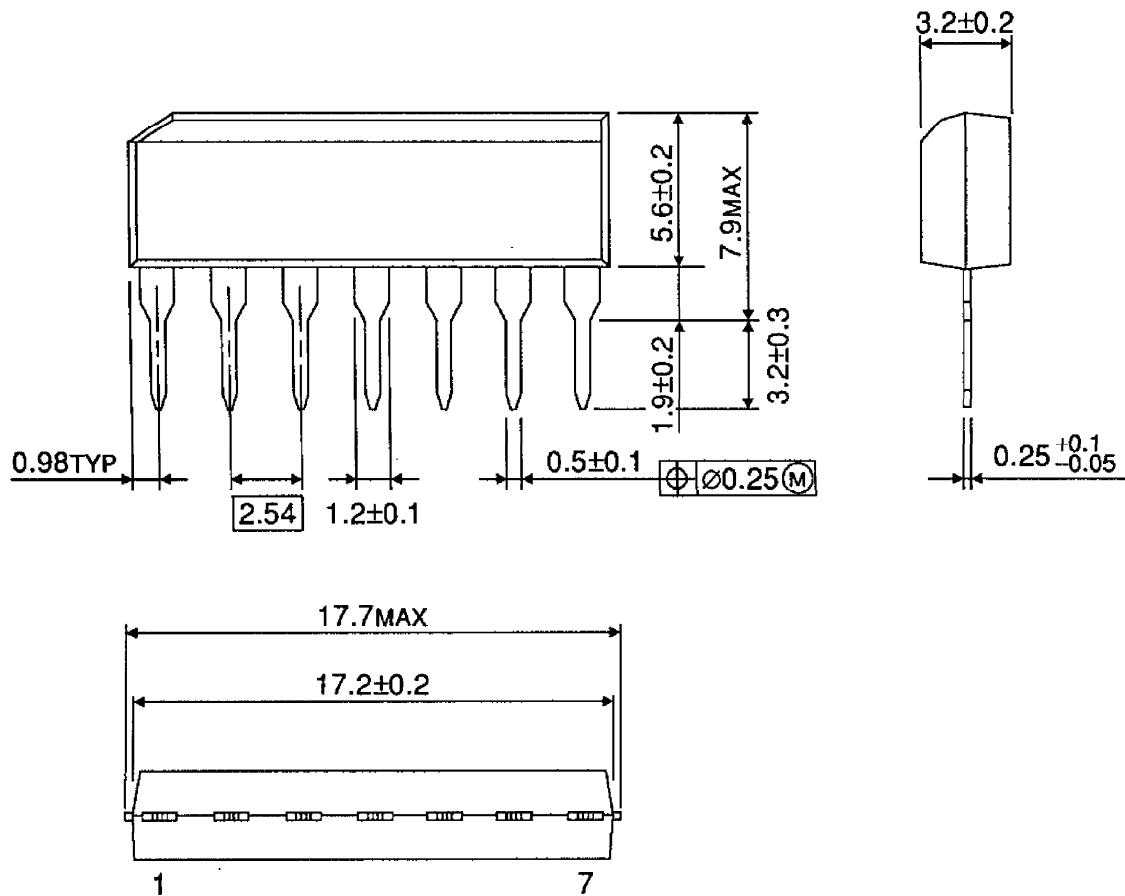
Unit : mm



Weight : 0.5g (Typ.)

PACKAGE DIMENSIONS
SIP7-P-2.54A

Unit : mm



Weight : 0.7g (Typ.)

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000707EBA

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